

ES1A THRU ES1J

1.0 AMP. Super Fast Surface Mount Rectifiers



Voltage Range 50 to 600 Volts Current 1.0 Ampere

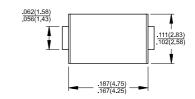
Features

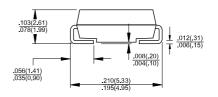
- \diamond Glass passivated junction chip
- \diamond For surface mounted application
- \diamond Low profile package
- \diamond Built-in strain relief,
- \diamond Ideal for automated placement
- Easy pick and place
- Superfast recovery time for high efficiency \diamond
- Glass passivated chip junction
- High temperature soldering:
- 250°C/10 seconds at terminals
- Plastic material used carries Underwriters Laboratory Classification 94V-O

Mechanical Data

- Cases: Molded plastic
- \diamond Terminals: Solder plated
- \diamond Polarity: Indicated by cathode band
- \diamond Packing: 12mm tape per E1A STD RS-481
- \diamond Weight: 0.064 gram

SMA/DO-214AC





Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	ES1A	ES1B	ES1C	ES1D	ES1F	ES1G	ES1H	ES1J	Units
Maximum Recurrent Peak Reverse Voltage	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current See Fig. 1	1.0								Α
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	30								Α
Maximum Instantaneous Forward Voltage @ 1.0A	0.95 1.3 1.7						V		
Maximum DC Reverse Current @ T _A =25°C at Rated DC Blocking Voltage @ T _A =100°C	5.0 100								uA uA
Maximum Reverse Recovery Time (Note 1)	35								nS
Typical Junction Capacitance (Note 2)	10 8						pF		
Maximum Thermal Resistance (Note 3) R θ JA R θ JL	85 35								°C/W
Operating Temperature Range T _J	-55 to +150								°C
Storage Temperature Range TSTG	-55 to + 150								°C

Notes: 1. Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A

- 2. Measured at 1 MHz and Applied VR=4.0 Volts
- 3. P.C.B. Mounted on 0.2 x 0.2"(5.0 x 5.0mm) Copper Pad Area.



RATINGS AND CHARACTERISTIC CURVES (ES1A THRU ES1J)

FIG.1- MAXIMUM FORWARD CURRENT DERATING **CURVE** 1.2 AVERAGE FORWARD CURRENT. (A) RESISTIVE OR 0.8 INDUCTIVE LOAD 0.2X0.2"(5.0X5.0mm) COPPER PAD AREAS 0.4 0.2 Λ 80 90 110 130 140 LEAD TEMPERATURE. (°C)

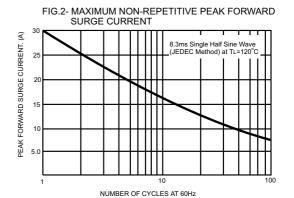


FIG.3- TYPICAL INSTANTANEOUS
FORWARD CHARACTERISTICS

TI=25°C
PULSE WIDTH-300µS
1% DUTY CYCLE

0.01
0.4
0.6
0.8
1.0
1.2
1.4
1.6
1.8
FORWARD VOLTAGE. (V)

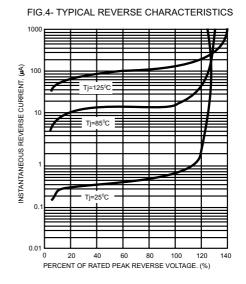


FIG.5- TYPICAL JUNCTION CAPACITANCE